

### **HV Start-up Green-mode PWM Controller with Brown-Out Protection**

### **General Description**

EM8671/A is a high performance, low cost, HV Start-up, current mode PWM controller with green mode power saving. The EM8671/A integrates functions of Soft Start(SS), Under Voltage Lockout(UVLO), Leading Edge Blanking(LEB), internal Over Temperature Protection(OTP), internal slope compensation. The EM8671/A also features more protection like Over Protection(OLP) and Over Voltage Protection(OVP) to prevent circuit damage occurred under abnormal conditions. The EM8671/A also has line under-voltage protection (Brown-out Protection).

### **Ordering Information**

Part Number	Package	Deep burst CS level
EM8671G	SOP-8	VE.0
EM8671G7	SOP-7	0.3V
EM8671AG	SOP-8	0.1V
EM8671AG7	SOP-7	0.1V

#### **Features**

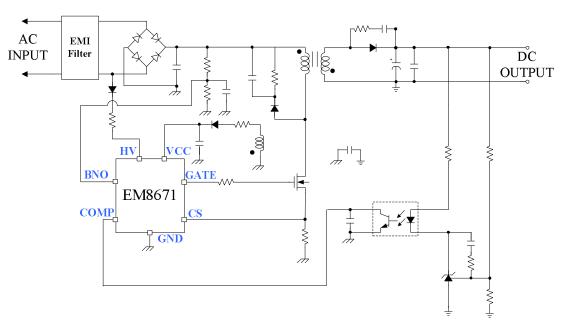


- 700V High Voltage Start up Circuit
- Current Mode Control
- Soft Start Function
- Built-in Slope Compensation
- Internal Leading-edge Blanking
- Brown in/out Protection
- Over Voltage Protection (OVP) on VCC pin
- Over Load Protection (OLP)
- Cycle-by-cycle Current Limit
- Feedback Open Protection
- Internal Over Temperature Protection (OTP)
- Constant Output Power Limit (Full AC Input Range)
- Excellent EMI performance

### **Applications**

- LCD Monitor Power Supply
- Open-Frame SMPS

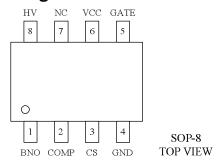
### **Typical Application Circuit**

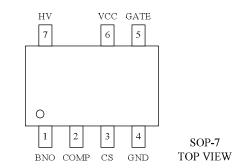






# **Pin Configuration**





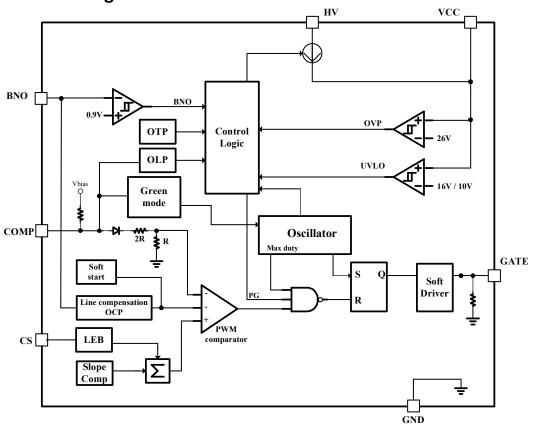
### **Pin Assignment**

Pin Name	Pin Number		Pin Function
	SOP-8	SOP-7	
GND	4	4	Ground.
СОМР	2	2	Voltage feedback pin. By connecting a photo-coupler to close the control loop and achieve the regulation.
BNO	1	1	Line voltage detection. Use for brown-out protection, and Line OCP compensation.
CS	3	3	Senses the primary current.
VCC	6	6	IC Power Supply Pin.
GATE	5	5	Gate drive output to drive the external MOSFET.
NC	7		No Internal Connection.
HV	7V I X I / I		For start-up, this pin is pulled high to the line input or the bulk capacitor via resistors.





# **Function Block Diagram**





### Absolute Maximum Ratings (Note1)

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Supply Input Voltage, VCC	30V
• Gate pin	30V
• HV pin	700V
• BNO, COMP, CS Pin	0.3V to 6.5V
• Power Dissipation, PD @ TA = $25^{\circ}$ C	
SOP 8	0.4W
SOP7	0.4W
Package Thermal Resistance	
SOP 8	160°C <b>/</b> W
SOP 7	160°C <b>/</b> W
Junction Temperature	150°C
• Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range	
<ul> <li>ESD Susceptibility (Note2)</li> </ul>	
HBM (Human Body Mode)	3KV
MM (Machine Mode)	250V
Gate Output Current	500mA
Recommended Operating Conditions (Note3)	
Supply Input Voltage, VCC	11V to 25V
• V <sub>CC</sub> Capacitor	4.7uF to 47uF
Junction Temperature Range	
Ambient Temperature Range	40°C to 105°C





# **Electrical Characteristics**

(V<sub>CC</sub>=16V,  $T_A$ =25 $^{\circ}$ C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
VCC Section						
VCC OVP Protect voltage	$V_{OVP}$		25	27	29	V
Start up current	I <sub>START</sub>	VCC=V <sub>TH-ON</sub> -0.5V	-	45	65	uA
VCC On Threshold Voltage	$V_{\text{TH-ON}}$		15	16	17	V
VCC Off Threshold Voltage	$V_{TH-OFF}$		9	10	11	V
Operating Supply Current 1	I <sub>CC-OP1</sub>	VCC=15V, V <sub>COMP</sub> =0V,	-	1	2	mA
Operating Supply Current 2	I <sub>CC-OP2</sub>	VCC=15V, V <sub>COMP</sub> =3V, C <sub>GATE</sub> =1nF	-	2.5	-	mA
Operating Supply Current 3	I <sub>CC-OP3</sub>	VCC=15V, Protection triggerred	-	0.5	-	mA
Gate Section						
Rising Time	$T_R$	C <sub>L</sub> = 1nF	-	100	160	nS
Falling Time	T <sub>F</sub>	C <sub>L</sub> = 1nF	-	30	60	nS
HV Section						
HV Current Source	I <sub>HV</sub>	/CC=V <sub>TH-ON</sub> -0.5V / <sub>HV</sub> =50V		1		mA
Off-State Leakage I <sub>leakage</sub>		VCC=V <sub>TH-ON</sub> +0.5V V <sub>HV</sub> =700V				uA
Current-Sense Section	•				•	
Maximum Internal Current		V <sub>BNO</sub> =1V	0.8	0.85	0.9	V
Setpoint	$V_{CSLim}$	V <sub>BNO</sub> =3V	0.65	0.7	0.75	V
Leading Edge Blanking Time	T <sub>LEB</sub>		200	300	400	nS
Propagation Delay Time	$T_PD$			100		nS
Soft-Start Period	T <sub>SS</sub>			2.5		mS
Internal Oscillator						
Oscillation Frequency	$f_{OSC}$		60	65	70	KHz
Maximum Duty	$D_{max}$			75		%
Green mode minimum frequency				22		KHz
Frequency variation vs. VCC		VCC=11V to 25V			5	%
Frequency variation vs. Temperature		-20°C to 105°C (Note4)			5	%
COMP Section						
COMP short to GND current	I <sub>COMP</sub>	V <sub>COMP</sub> =0V	150	250	350	uA
Open loop COMP voltage	$V_{COMP}$	COMP pin open		5.2		V
COMP voltage to CS voltage Attenuation	Av		1 / 2.5	1/3	1/3.5	V/V



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Green mode COMP Threshold Voltage	$V_{Green}$		1.8		V
COMP voltage for zero duty	V <sub>COMP-ZD</sub>		1.3		V
BNO Section					
PWM Turn On Voltage	V <sub>BNO-ON</sub>	0.81	0.86	0.91	V
PWM Turn Off Voltage	V <sub>BNO_OFF</sub>		V <sub>BNO-ON</sub> – 0.1		V
Protection Section					
Open loop protection delay time	$T_{delay}$		56		mS
Open loop protection COMP Trip voltage	V <sub>OLP</sub>		4.0		V
Internal Temperature Shutdown	$T_SD$		140		$^{\circ}\mathbb{C}$

- **Note 1.** Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- **Note 2.** Devices are ESD sensitive. Handling precaution is recommended.
- **Note 3.** The device is not guaranteed to function outside its operating conditions.
- Note 4. Guaranteed by design.

### **Typical Operating Characteristics**

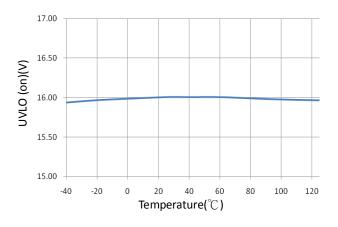


Fig1. UVLO (on) vs. Temperature

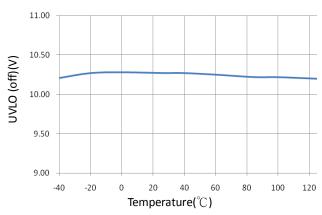


Fig2. UVLO (off) vs. Temperature

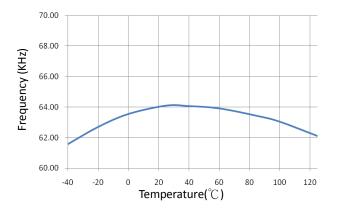


Fig3. Frequency vs. Temperature.

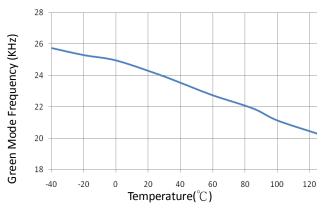


Fig4. Green Mode Frequency vs. Temperature.

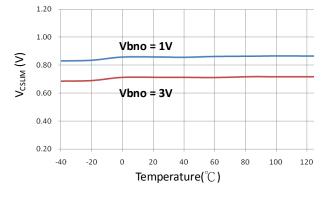


Fig5. V<sub>CSLIM</sub> vs. Temperature.

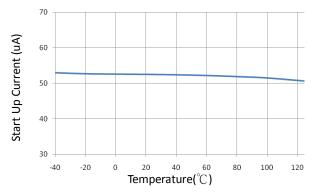


Fig6. Start Up Current vs. Temperature.



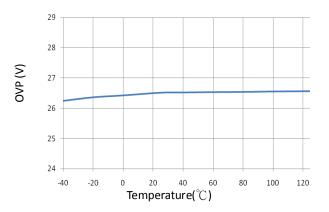


Fig7. OVP vs. Temperature.

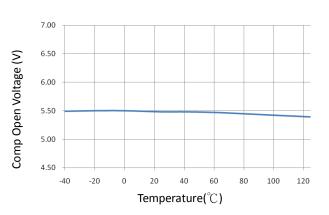


Fig9. Comp Open Voltage vs. Temperature.

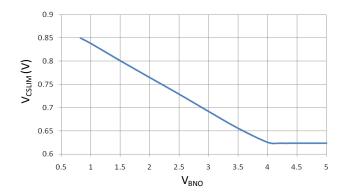


Fig11. V<sub>CSLIM</sub> vs. V<sub>BNO</sub>.

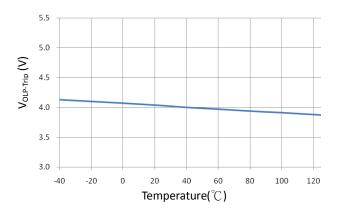


Fig8. V<sub>OLP-Trip</sub> vs. Temperature.

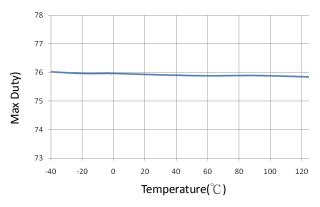


Fig10. Max Duty vs Temperature.

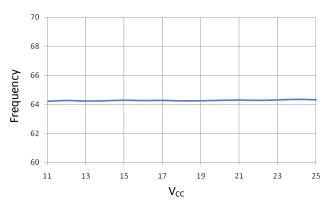
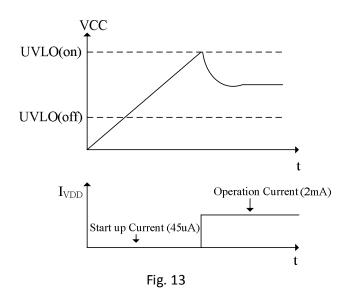


Fig12. Frequency vs. V<sub>CC</sub>.



# Functional Description

An UVLO comparator is implemented in EM8671/A to monitor the VCC pin voltage. As shown in Fig. 13, a hysteresis is built in to prevent the shutdown from the voltage drop during startup. The UVLO (on) and UVLO (off) are setting at 16V and 10V, respectively.



#### **Startup Operation**

Fig. 14 shows a typical HV startup circuit and transformer auxiliary winding for the EM8671/A application, it consumes only startup current (typical 45uA) and the startup current drawn from the HV pin to charge the VCC capacitor (C<sub>VCC</sub>). When VCC reaches UVLO (on) voltage, EM8671/A begins switching and the HV startup current switches off. Then, the power required is supplied from the transformer auxiliary winding. The hysteresis of UVLO (off) provides more holdup time, which allows using a small capacitor for VCC.

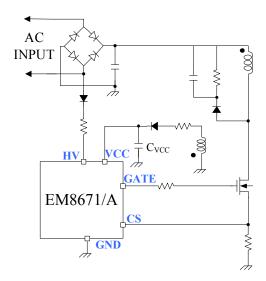


Fig. 14

#### **Switching Frequency**

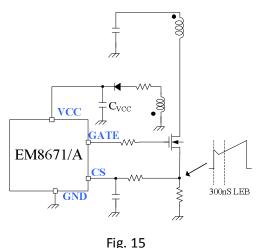
To guarantee accurate frequency, EM8671/A is trimmed to 7% tolerance. The internal oscillator also generates slope compensation, 75% maximum duty limit.

#### Leading Edge Blanking (LEB)

Each time the power MOSFET turn on, the MOSFET C<sub>OSS</sub>, secondary rectifier reverse recovery current and gate driver sourcing current comprise the current spike. To avoid premature termination of the switching pulse, a leading edge blanking time is built in. During the blanking time (300nS), the PWM comparator is off and cannot switch off the gate driver. It is recommended to adopt a smaller R-C filter (as show ad Fig.15) for high power application to avoid the total spike width over 300nS leading edge blanking time.







#### **Soft Start**

The EM8671/A has an internal soft-start circuit that increases cycle-by-cycle current limit comparator inverting input voltage slowly after it starts. The typical soft-start time is 2mS. The pulse width to the power MOSFET is progressively increased to establish the correct working conditions for transformers, rectifier diodes and capacitors. The voltage on the output capacitors is progressively increased with the intention of smoothly establishing the required output voltage. It also helps prevent transformer saturation and reduces the stress on the secondary diode during startup.

#### Slope compensation

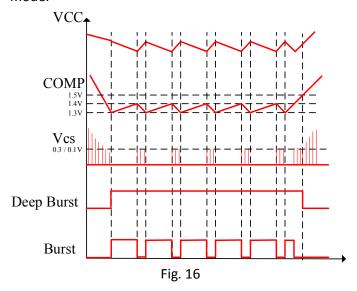
In the conventional application, the problem of the stability is a critical issue for current mode controlling, when it operates in high than 50% of the duty cycle. The EM8671/A built in saw-tooth slope compensation. So it requires no extra component.

#### **Deep Burst Mode Operation**

At no load or light load condition, majority of the power dissipation in switching power supply is form switching loss on the power MOSFET, the core loss of the transformer and the loss on the snubber. The magnitude of power loss is in proportion to the number of switching events within a fixed period of time. Reducing switching events leads reduction on the power loss and

#### conserves the energy.

The EM8671/A adjusts the switching mode according to the load condition, the COMP pin voltage drops below Deep Burst mode in-threshold level (typical 1.3V). Device enters Deep Burst Mode Control. The Gate drive output remains at off state to minimize the switching loss and reduces the standby power consumption. And when the COMP pin voltage exceed the burst mode on threshold level (typical 1.4V). The Gate drive output starts active. The COMP pin voltage immediately increases if there is a high load. When the COMP pin voltage exceed the Deep Burst mode out-threshold level (typical 1.5V), the device goes to normal mode. During the Deep Burst mode, the CS level is controlled to 0.3V for EM8671. (0.1V for EM8671A) Fig 16 shows the signals of Deep Burst mode.



#### **Protection**

The EM8671/A provides many protection functions that intend to protect system from being damaged. All the protection functions are listed as below:

#### Cycle-by-cycle current limit

The EM8671/A has over-current protection thresholds. It is for cycle-by-cycle current limit, which turns off MOSFET for the remainder of the switching cycle when the sensing voltage of MOSFET current reaches the threshold.



#### Over-load / Open-loop Protection (OLP)

When feedback loop is open, as shown in Fig. 17, no current flows through the opto-coupler transistor, the EM8671/A pulls up the COMP pin voltage to 5.2V.

When the COMP pin voltage is above 4.0V longer than 56mS, OLP is triggered. This protection is also triggered when the SMPS output drops below the normal value longer than 56mS due to the overload condition.

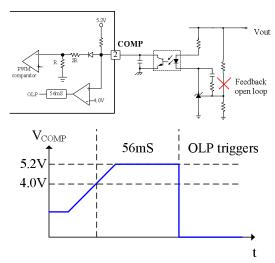
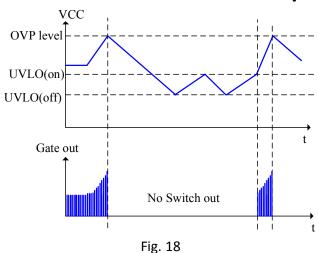


Fig. 17

#### Over Voltage Protection (OVP) on VCC

The  $V_{GS}$  ratings of the HV power MOSFETs are often limited up to max 30V. To prevent the  $V_{GS}$  from the fault condition, the EM8671/A are implemented a Over-Voltage-Protection (OVP) on VCC. Whenever the VCC voltage is high than the OVP threshold voltage (28V), the output gate drive will be shutdown to shop the switching of the power MOSFET until the next UVLO (on).

The Over-Voltage-Protection on VCC function in EM8671/A is an auto-restart type protection. If the OVP condition is not released, the VCC will tripped the OVP level again and re-shutdown the gate output. The VCC is working as a hiccup mode as shown in Fig. 18. On the other hand, if the OVP condition is removed, the VCC level will go back to normal level and the output will automatically return to the normal operation.



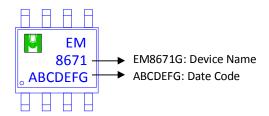
#### Internal Over-Temperature Protection (OTP)

Internal 140°C comparator will provide over temperature protection (OTP). OTP will not shutdown system. It stops the system from switching until the VCC is below the UVLO (off) threshold voltage, the system will hiccup.

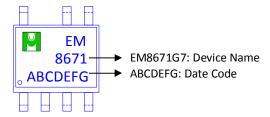


# **Ordering & Marking Information**

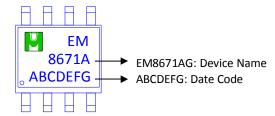
Device Name: EM8671G for SOP-8



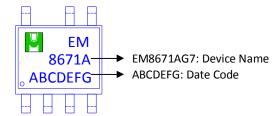
Device Name: EM8671G7 for SOP-7

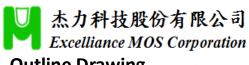


Device Name: EM8671AG for SOP-8

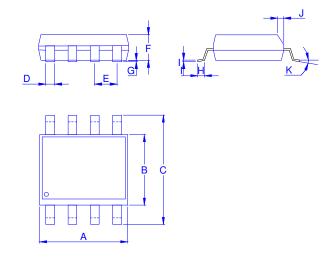


Device Name: EM8671AG7 for SOP-7





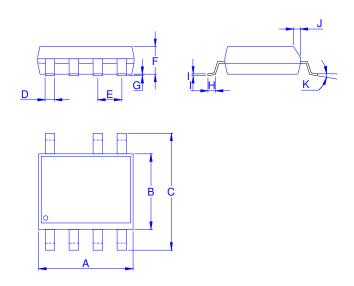
# Outline Drawing SOP-8



#### Dimension in mm

Dimension	Α	В	С	D	E	F	G	Н	1	J	K
Min.	4.70	3.70	5.80	0.33		1.20	0.08	0.40	0.19	0.25	0°
Тур.					1.27						
Max.	5.10	4.10	6.20	0.51		1.62	0.28	0.83	0.26	0.50	8°

### SOP-7



#### Dimension in mm

Dimension	Α	В	С	D	E	F	G	Н	I	J	K
Min.	4.70	3.70	5.80	0.33		1.20	0.08	0.40	0.19	0.25	0°
Тур.					1.27						
Max.	5.10	4.10	6.20	0.51		1.62	0.28	0.83	0.26	0.50	8°